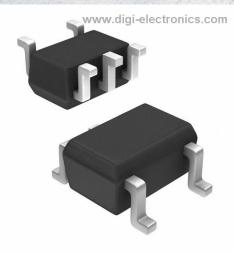


74AHC1G04SE-7 Datasheet



DiGi Electronics Part Number Manufacturer Manufacturer Product Number Description Detailed Description 74AHC1G04SE-7-DG Diodes Incorporated 74AHC1G04SE-7 IC INVERTER 1CH 1-INP SOT353 Inverter IC 1 Channel SOT-353

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
74AHC1G04SE-7	Diodes Incorporated
Series:	Product Status:
74AHC	Active
Logic Type:	Number of Circuits:
Inverter	1
Number of Inputs:	Features:
1	-
Voltage - Supply:	Current - Quiescent (Max):
2V ~ 5.5V	1 μΑ
Current - Output High, Low:	Input Logic Level - Low:
8mA, 8mA	0.5V ~ 1.65V
Input Logic Level - High:	Max Propagation Delay @ V, Max CL:
1.5V ~ 3.85V	7.5ns @ 5V, 50pF
Operating Temperature:	Mounting Type:
-40°C ~ 125°C	Surface Mount
Supplier Device Package:	Package / Case:
SOT-353	5-TSSOP, SC-70-5, SOT-353
Base Product Number:	
74AHC1G04	

Environmental & Export classification

8542.39.0001

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



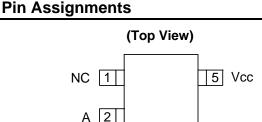
SINGLE INVERTER GATE

4 Y

Description

The 74AHC1G04 is a single inverter gate with a standard push-pull output. The device is designed for operation with a power supply range of 2.0V to 5.5V. The gate performs the positive Boolean function:

$$Y = \overline{A}$$



Features

- Supply Voltage Range from 2.0V to 5.5V
- ± 8 mA Output Drive at 5.0V
- CMOS low power consumption
- Schmitt Trigger Action at Input Makes the Circuit Tolerant for Slower Input Rise and Fall Time
- ESD Protection per JESD 22
 - o Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- SOT25 and SOT353: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish / RoHS Compliant (Note 1)

Applications

• General Purpose Logic

GND 3

- Wide array of products such as:
 - PCs, networking, notebooks, netbooks, PDAs

SOT25 / SOT353

- $\circ~$ Computer peripherals, hard drives, CD/DVD ROM
- $\circ~$ TV, DVD, DVR, set top box
- o Personal Navigation / GPS
- o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

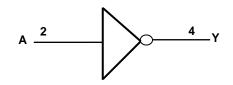


SINGLE INVERTER GATE

Pin Descriptions

Pin Name	Pin NO.	Description			
NC	1	No Connection			
A	2	Data Input			
GND	3	Ground			
Y	4	Data Output			
V _{CC}	5	Supply Voltage			

Logic Diagram



Function Table

Inputs	Output
Α	Y
Н	L
L	Н



SINGLE INVERTER GATE

Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current VI<0	-20	mA
I _{OK}	Output Clamp Current ($V_0 < 0$ or $V_0 > V_{CC}$)	±20	mA
lo	Continuous output current ($V_0 = 0$ to V_{CC})	±25	mA
I _{CC}	Continuous current through V _{CC}	50	mA
I _{GND}	Continuous current through GND	-50	mA
ТJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 3)

Symbol		Parameter	Min	Max	Unit
V _{CC}	Operating Voltage		2	5.5	v
		$V_{CC} = 2V$	1.5		
VIH	High-level Input Voltage	$V_{CC} = 3V$	2.1		V
		$V_{CC} = 5.5V$	3.85		
		$V_{CC} = 2V$		0.5	
VIL	Low-level input voltage	$V_{CC} = 3V$		0.9	V
		$V_{CC} = 5.5V$		1.65	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
		$V_{CC} = 2V$		-50	uA
I _{OH}	High-level output current	$V_{CC} = 3.3V \pm 0.3V$		-4	- mA
		$V_{CC} = 5V \pm 0.5V$		-8	mA
		$V_{CC} = 2V$		50	uA
I _{OL}	Low-level output current	$V_{CC} = 5V \pm 0.5V$		4	
		$V_{CC} = 3V$		8	mA
Δt/ΔV	Input transition rise or fall	$V_{CC} = 3.3V \pm 0.3V$		100	ns/V
Δι/Δν	rate	$V_{\rm CC} = 5V \pm 0.5V$		20	115/ V
T _A	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at $V_{\text{CC}} \mbox{ or Ground}.$



SINGLE INVERTER GATE

Electrical Characteristics

		Tako Internet			25⁰C		-40ºC t	o 85⁰C	-40°C t	o 125⁰C	
Symbol	Parameter	Test Conditions	V _{CC}	Min	Тур.	Max	Min	Max	Min	Max	Unit
			2V	1.9	2		1.9		1.9		
		Ι _{ΟΗ} = -50μΑ	3V	2.9	3		2.9		2.9		
V _{OH}	High Level		4.5V	4.4	4.5		4.4		4.4		V
-	Output Voltage	I _{OH} = -4mA	3V	2.58			2.48		2.40		
		I _{OH} = -8mA	4.5V	3.94			3.8		3.70		
			2V			0.1		0.1		0.1	
		I _{OL} = 50μA	3V			0.1		0.1		0.1	
V _{OL}	Low Level Output Voltage		4.5V			0.1		0.1		0.1	V
		$I_{OL} = 4mA$	3V			0.36		0.44		0.55	
		$I_{OL} = 8mA$	4.5V			0.36		0.44		0.55	
l _l	Input Current	$V_1 = 5.5 V \text{ or GND}$	0 to 5.5V			± 0.1		± 1		±2	μA
I _{CC}	Supply Current	V _I = 5.5V or GND I _O =0	5.5V			1		10		40	μA
CI	Input Capacitance	$V_{I} = V_{CC} - or GND$	5.5V		2.0	10		10		10	pF
0	Thermal Resistance	SOT25	(Nata 4)		195						°C/W
θ_{JA}	Junction-to- Ambient	SOT353	(Note 4)		430						C/VV
θ _{JC}	Thermal Resistance	SOT25	(Note 4)		58						°C ///
olC	Junction-to- Case	SOT353	(11018 4)		155						°C/W

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout

Switching Characteristics

V_{CC} = 3.3 V ± 0.3 (see Figure 1)

Deremeter	From	то			25⁰C		-40ºC t	o 85⁰C	-40°C to	o 125⁰C	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
	t _{pd} A	V	C _L =15pF	0.6	4.3	7.1	0.6	8.5	0.6	11.0	ns
t _{pd}		A	ř	C _L =50pF	0.6	6.1	10.6	0.6	12.0	0.6	14.5

V_{CC} = 5 V ± 0.5V (see Figure 1)

Parameter	From TO		From TO 25°C		-40°C to 85°C		-40°C to 125°C		Unit				
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit		
.	i A	t. Δ		V	C _L =15pF	0.6	3.1	5.5	0.6	6.5	0.6	7.0	ns
t _{pd}		ř	C _L =50pF	0.6	4.5	7.5	0.6	8.5	0.6	9.5	ns		



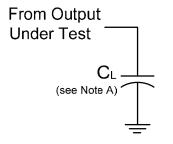
SINGLE INVERTER GATE

Operating Characteristics

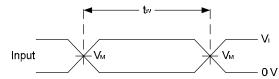
T_A = 25 °C

Parameter		Test Conditions	V _{CC} = 5V Typ.	Unit
C _{pd}	Power dissipation capacitance	f = 1 MHz No Load	12	pF

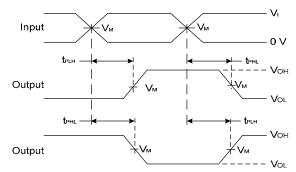
Parameter Measurement Information



V _{cc}	In	puts	V _M	CL	
•00	VI	t _r /t _f	• IVI	υL	
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	15pF	
5V±0.5V	V _{CC}	≤3ns	V _{CC} /2	15pF	
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	50pF	
5V±0.5V	V _{CC}	≤3ns	V _{CC} /2	50pF	







Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

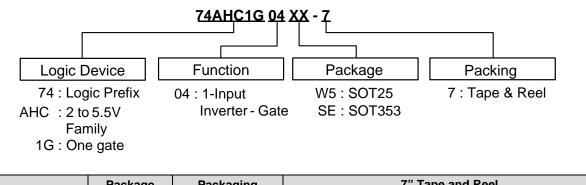
Figure 1. Load Circuit and Voltage Waveforms

- Notes: A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate \leq 1 MHz.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLH} and t_{PHL} are the same as t_{PD.}



SINGLE INVERTER GATE

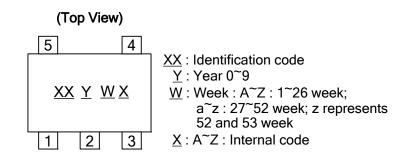
Ordering Information



	Davias	Package Packaging		7" Tape and Reel			
	Device	Code	(Note 5)	Quantity	Part Number Suffix		
Pb	74AHC1G04W5-7	W5	SOT25	3000/Tape & Reel	-7		
Pb,	74AHC1G04SE-7	SE	SOT353	3000/Tape & Reel	-7		

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

Marking Information



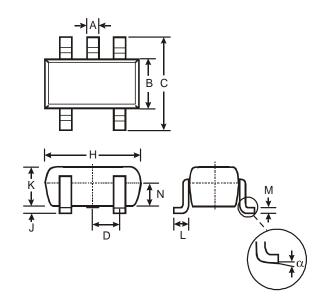
Part Number	Package	Identification Code
74AHC1G04W5	SOT25	ΥT
74AHC1G04SE	SOT353	ΥT



SINGLE INVERTER GATE

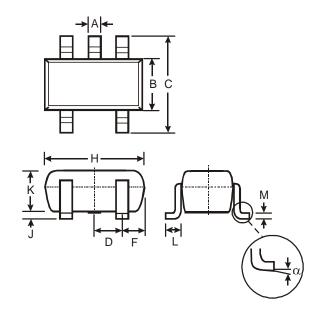
Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



SOT25					
Dim	Min	Max	Тур		
Α	0.35	0.50	0.38		
В	1.50	1.70	1.60		
C	2.70	3.00	2.80		
D			0.95		
Н	2.90	3.10	3.00		
ب	0.013	0.10	0.05		
K	1.00	1.30	1.10		
L	0.35	0.55	0.40		
Μ	0.10	0.20	0.15		
Ν	0.70	0.80	0.75		
α	0°	8°			
All Dimensions in mm					

(2) Package Type: SOT353



SOT353				
Dim	Min	Max		
Α	0.10	0.30		
В	1.15	1.35		
С	2.00	2.20		
D	0.65 Тур			
F	0.40	0.45		
Н	1.80	2.20		
J	0	0.10		
κ	0.90	1.00		
L	0.25	0.40		
М	0.10	0.22		
α	0°	8°		
All Dimensions in mm				



SINGLE INVERTER GATE

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